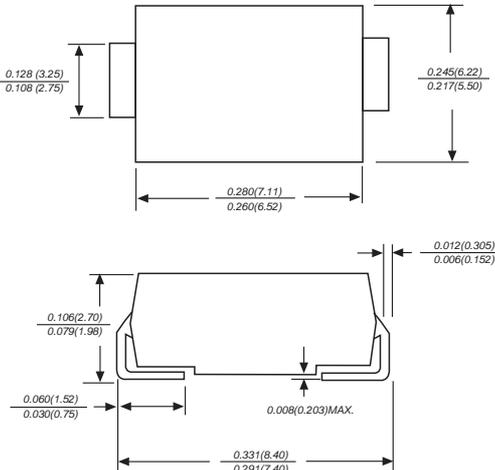


## I. General Purpose Rectifier

### 10.0A Surface Mount Silicon Rectifier S10A~S10M

(Package: SMC ( DO-214AB))

<p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>• The plastic package carries Underwriters Laboratory Flammability Classification 94V-0</li> <li>• For surface mounted applications</li> <li>• Low reverse leakage</li> <li>• Built-in strain relief, ideal for automated placement</li> <li>• High forward surge current capability</li> <li>• High temperature soldering guaranteed : 250 /10 seconds at terminals</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>• Case : JEDEC DO-214AB molded plastic body</li> <li>• Terminals : Solder plated, solderable per MIL-STD-750, Method 2026</li> <li>• Polarity : Color band denotes cathode end</li> <li>• Mounting Position : Any</li> <li>• Weight : 0.220 grams</li> </ul>	 <p>Case: SMC Dimensions in inches and (millimetres)</p>
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## Ratings & Electrical Characteristics

Ratings at 25 ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	S10A	S10B	S10D	S10G	S10J	S10K	S10M	Units
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current at $T_L = 65$	$I_o$	10.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	400.0							Amps
Maximum instantaneous forward voltage at 10.0A	$V_F$	1.0							Volts
Maximum DC reverse current $T_a = 25$ at rated DC blocking voltage $T_a = 100$	$I_R$	5.0 100.0							$\mu A$ $\mu A$
Typical junction capacitance (Note 1)	$C_j$	130.0							PF
Typical thermal resistance (Note 2)	$R_{th-JA}$	10.0							/W
Operating junction and storage temperature range	$T_j, T_{stg}$	-65 to + 150							

Notes:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.6x0.6" (16x16mm) copper pad areas

<http://patron-components.com/>

# Ratings and Characteristic Curves of S10A~S10M

FIG. 1- FORWARD CURRENT DERATING CURVE

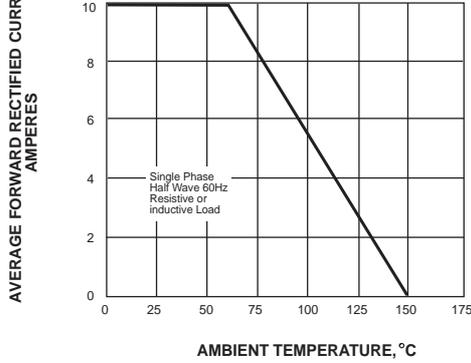


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

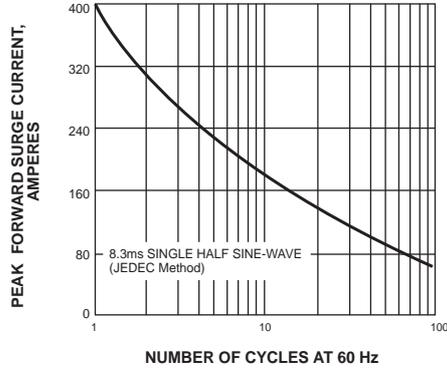


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

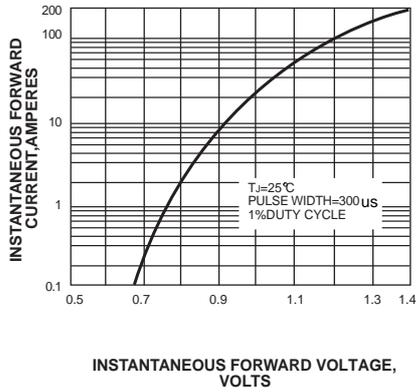


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

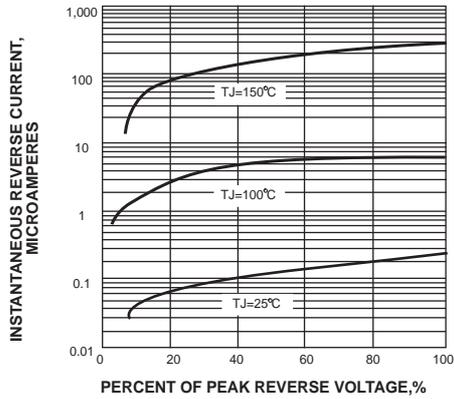


FIG. 5-TYPICAL JUNCTION CAPACITANCE

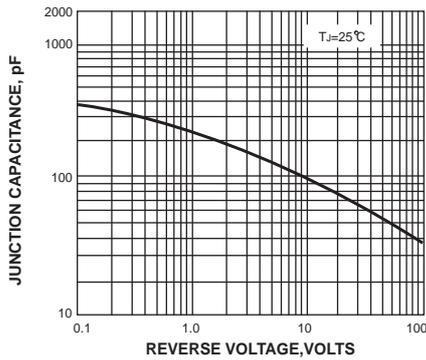


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

